SEMICONDUCTOR

Technical Data Data Sheet M2940, Rev. A

MBR20135/150CT SCHOTTKY RECTIFIER

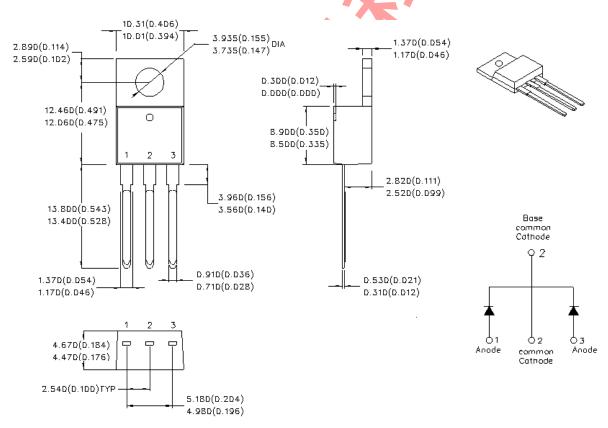
Applications:

• Switching power supply • Converters • Free-Wheeling diodes • Reverse battery protection

Features:

- 150 °C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- . Guard ring for enhanced ruggedness and long term reliability

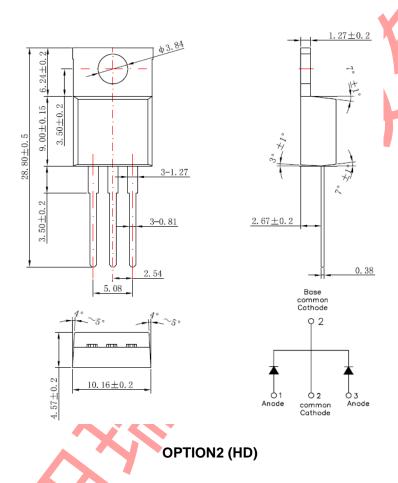
Mechanical Dimensions: In Inches / mm



OPTION 1 (CJ)

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TO-220AB

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Maximum Ratings:

Characteristics	Symbol	Condition		Max.	Units
Peak Inverse Voltage	V_{RWM}	-	135	MBR20135CT	V
			150	MBR20150CT	
Max. Average Forward	I _{F(AV)}	50% duty cycle @T _C =133℃,		10(Per leg)	Α
		rectangular wave form	2	0(Per device)	
Max. Peak One Cycle Non-Repetitive			/ /.		
Surge Current	I _{FSM}	8.3 ms, half Sine pulse		150	Α
(per leg)					

Electrical Characteristics:

Characteristics	Symbol	Condition		Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 10A, Pulse, T _J = 25 ℃		0.90	V
(per leg)*		@ 20 A, Pulse, T _J = 25 °C		1.00	
	V_{F2}	@ 10 A, Pulse, T _J = 125 ℃		0.83	V
		@ 20 A, Pulse, T _J = 125 ℃		1.00	
Max. Reverse Current	I _{R1}	@V _R = rated VR	Max.	0.50	mA
(per leg)*		T _J = 25 ℃	Typical	0.01	
	I _{R2}	@V _R = rated VR		5.0	mA
		T _J = 125 ℃			
Max. Junction Capacitance	Ст	@V _R = 5V, T _C = 25 °C		400	pF
(per leg)		f _{SIG} = 1MHz			
Typical Series Inductance	Ls	Measured lead to lead 5 mm from p	8.0	nΗ	
(per leg)					
Max. Voltage Rate of Change	dv/dt	-		10,000	V/ s

^{*} Pulse Width < 300µs, Duty Cycle <2%

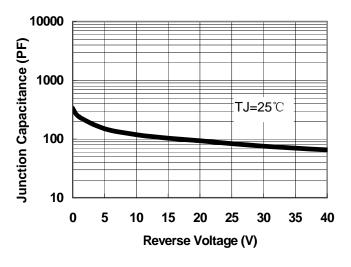
Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units	
Max. Junction Temperature	TJ	-	-55 to +150	$^{\circ}$ C	
Max. Storage Temperature	T _{stg}	-	-55 to +150	${\mathbb C}$	
Maximum Thermal Resistance Junction to Case (per leg)	$R_{\theta JC}$	DC operation	2.0	°C/W	
Maximum Thermal Resistance Junction to Case (per package)	$R_{\theta JC}$	DC operation	1.0	°C/W	
Maximum Thermal Resistance, Case to Heat Sink	R _{ecs}	Mounting surface, smooth and greased(only for TO-220)	0.50	°C/W	
Approximate Weight	wt	-	2	g	
Mounting Torque	T _M	-	6(Min.) 12(Max.)	Kg-cm	
Case Style	TO-220AB				

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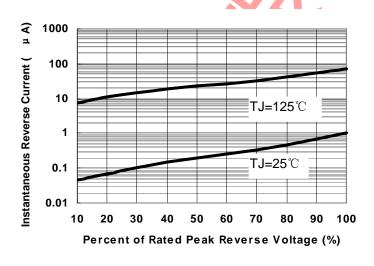


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

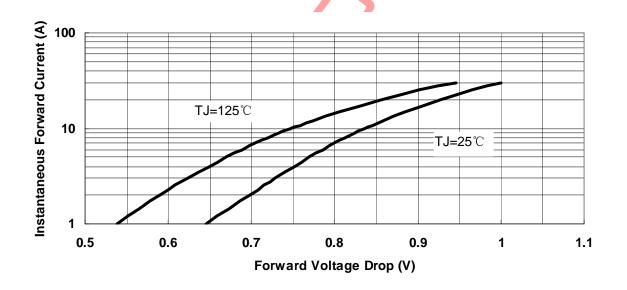


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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